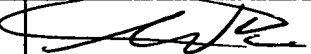


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	Application Number	10/849,348
	Filing Date	May 19, 2004
	First Named Inventor	Robert H. Burgener, II
	Group Art Unit	
	Examiner Name	
	Attorney Docket Number	3398.2.10

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials *	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
W/S	O1	Itani, Kenya, et al., "Low-Dislocation-Density GaAs Wafers Grown by Vertical Gradient Freeze Process, Suitable for Mass Production of Semiconductor Lasers," Hitachi Cable Review No. 20, August 2001, pp. 35-38	
	O2	Look, D.C., et al. "The Future of ZnO Light Emitters," Phys. Stat. Sol. (2004), pp. 1-10	
	O3	Pearlton, S.J., et al. "Wide Band Gap Ferromagnetic Semiconductors and Oxides," Journal of Applied Physics Vol. 93, No. 1, January 1, 2003, pp. 1-13	
	O4	Web Page '99 SBIR Phase I... Topic 14 - Electronic Materials, http://www-ee.eng.buffalo.edu/faculty/paololin/492/semicon.pdf , "Low-Temperature Hydrothermal Growth of ZnO for Semiconductor Substrates," 2/26/04, 2 pages	
	O5	Web Page "Semiconductor Photonics", 3 pages	

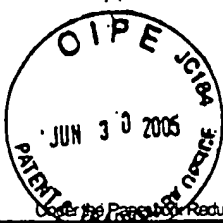
Examiner Signature		Date Considered	8/31/05
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		Application Number	10/849,348
		Filing Date	May 19, 2004
		First Named Inventor	Robert H. Burgener, II
		Group Art Unit	
		Examiner Name	
		Attorney Docket Number	3398.2.10

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number - Kind Code ² (if known)			
WSL	U1	US-3,664,867-B1	05/23/1972	Galli et al.	
WSL	U2	US-4,399,441-B1	08/16/1983	Vaughn et al.	

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ³
		Country Code ² - Number ⁴ - Kind Code ⁵ (if known)				
WSL	F1	EP - 1219731-A1	07/03/2002	Yoshida, et al.		
WSL	F2	JP 2002-68890-AI	03/08/2002	Ogata, et al.		

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